

Characteristics of a PV module

Manufacturer, model : **Trina Solar, TSM-490DE18M(II)**

Availability : Prod. Since 2020

Data source : UL 2020

STC power (manufacturer)	Pnom	490 Wp	Technology	Si-mono
Module size (W x L)	1.102 x 2.187	m ²	Rough module area	Amodule 2.41 m ²
Number of cells	2 x 75		Sensitive area (cells)	Acells 2.21 m ²

Specifications for the model (manufacturer or measurement data)

Reference temperature	TRef	25 °C	Reference irradiance	GRef	1000 W/m ²
Open circuit voltage	Voc	51.3 V	Short-circuit current	Isc	12.14 A
Max. power point voltage	Vmpp	42.4 V	Max. power point current	Imp	11.56 A
=> maximum power	Pmpp	490.1 W	Isc temperature coefficient	mulsc	6.2 mA/°C

One-diode model parameters

Shunt resistance	Rshunt	300 ohm	Diode saturation current	IoRef	0.013 nA
Serie resistance	Rserie	0.24 ohm	Voc temp. coefficient	MuVoc	-157 mV/°C
Specified Pmax temper. coeff.	muPMaxR	-0.36 %/°C	Diode quality factor	Gamma	0.97
			Diode factor temper. coeff.	muGamma	-0.001 1/°C

Reverse Bias Parameters, for use in behaviour of PV arrays under partial shadings or mismatch

Reverse characteristics (dark)	BRev	3.20 mA/V ²	(quadratic factor (per cell))	
Number of by-pass diodes per module		3	Direct voltage of by-pass diodes	-0.7 V

Model results for standard conditions (STC: T=25° C, G=1000 W/m², AM=1.5)

Max. power point voltage	Vmpp	42.7 V	Max. power point current	Imp	11.49 A
Maximum power	Pmpp	490.5 Wc	Power temper. coefficient	muPmpp	-0.35 %/°C
Efficiency(/ Module area)	Eff_mod	20.4 %	Fill factor	FF	0.788
Efficiency(/ Cells area)	Eff_cells	22.2 %			

